

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	23	lingren.in.	USPAT	OR	OFF	2005/10/11 10:19
L2	1	10/629676	US-PGPUB	OR	OFF	2005/10/11 11:14
L3	4	(radiation adj detector) and tft and electrode and selenium and glass and semiconductor and wavelength and halogen and substrate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/11 10:19
L4	5	(radiation adj detector) and tft and electrode and selenium and glass and semiconductor and wavelength and halogen and substrate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/11 10:19
L5	35	shulz.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/11 10:19
L6	12899	schulz.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/11 10:19
L7	83	L6 and reiner.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/11 10:19
L8	45	L7 and siemens	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/11 10:19
L9	3	L7 and (diagnostic near apparatus). ti.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/11 10:19
L10	6	(radiation adj detector) and ((light with (wavelength with (band adj gap))) with semiconductor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/11 10:19

L11	1578	(radiation adj detector) and 250/370.12 or 250/370.09	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/11 10:19
L12	65	L11 and (electrode with semiconductor) and (light with source)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/11 10:19
L13	8	L12 and transmittance	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/11 10:57
L14	1009	(250/370.12 or 250/370.09).ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/11 10:59
L15	392	14 and ((semiconductor or substrate) same electrode)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/11 10:59
L16	26	15 and ((wavelength or light) same ((band adj gap) or bandgap))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/11 11:04
L17	6	14 and (split near electrode)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/11 11:02
L18	2	16 and (split near electrode)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/11 11:02

L19	0	15 and ((wavelength or light) same transmittance)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/11 11:04
L20	12	15 and ((wavelength or light) same transmittance)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/11 11:05
L21	4	16 and 20	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/11 11:08
L22	64	(semiconductor and electrode and source and wavelength and ((band adj gap) or bandgap)).clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/11 11:09
L23	28	(semiconductor and electrode and source and wavelength and ((band adj gap) or bandgap)).clm.	US-PGPUB	OR	ON	2005/10/11 11:10
L24	1	(semiconductor and electrode and source and transmittance and wavelength and ((band adj gap) or bandgap)).clm.	US-PGPUB	OR	ON	2005/10/11 11:10
L25	2	(semiconductor and electrode and source and transmittance and wavelength and ((band adj gap) or bandgap)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/11 11:13
L26	1	("5937027").PN.	USPAT	OR	OFF	2005/10/11 11:13
L27	2	"20010025938" or "20040022352"	US-PGPUB	OR	OFF	2005/10/11 11:14